

Surface Mount Surge Suppressors Bridge **FEATURES**:

- · Lower clamping voltage and excellent performance on ringing waves testing.
- Green Molding Compound (No Halogen and Antimony)
- Glass Passivated Chip Junction
- · High Surge Current Capability
- Designed for Surface Mount Application

MECHANICAL DATA

· Case: UMBT

• Terminals: Solderable per MIL-STD-750, Method 2026 Approx. Weight: 60mg/0.0021oz

Maximum Ratings and Electrical characteristics

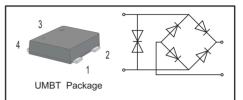
Ratings at 25 °C ambient temperature unless otherwise specified.

Single phase half-wave 60 Hz, resistive or inductive load, for capacitive load current derate by 20 %.

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Jingdao Microelectronics co.LTD

PINNING

PIN	DESCRIPTION			
1	Input Pin (~)			
2	Input Pin (~)			
3	Output Anode (+)			
4	Output Cathode (-)			



Parameter of Bridge Rectifier	Symbols	STB110BS	Units
Average Rectified Output Current @ Fig.1	Io	1.0	Α
Peak Forward Surge Current 8.3 ms Single Half Sine Wave Superimposed on Rated Load (JEDEC Method)	I _{FSM}	30	А
Maximum Forward Voltage at 1.0 A	V _F	1.1	V
	I _R	5 40	μΑ
Typical Junction Capacitance (Note1)	Cj	7	pF
Typical Thermal Resistance (Note2)	$egin{array}{c} R_{ heta JA} \ R_{ heta JC} \ R_{ heta JL} \end{array}$	45 15 25	°C/W
Operating and Storage Temperature Range	T_{j},T_{stg}	-55 ~ +150	°C

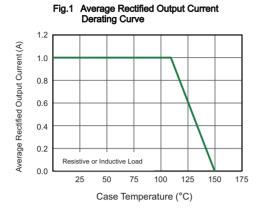
Note: 1. Measured at 1MHz and applied reverse voltage of 4 V D.C.

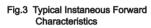
2. Mounted on glass epoxy PC board with 4×1.5"×1.5" (3.81×3.81 cm) copper pad.

Parameter of TVS		STB110BS	Unit
Maximum allowable continuous AC voltage at 50-60Hz		125	V
Breakdown Voltage at 1mA		190~240	V
Maximum allowable continuous DC voltage		170	V
Maximum allowable clamping voltage		300	V
Maximum peak current (8/20μs@2Ω)		200	А
Operating Junction Temperature and Storage Temperature Range		-55 ~ +150	°C

NOTES:

- 1. The breakdown voltage was measured at 1mA
- 2. The clamping voltage was measured at 8/20µs standard current, (1A)
- 3. The peak current was tested at 8/20µs waveform





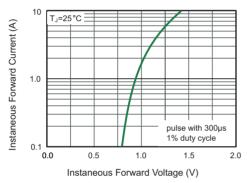


Fig.5 Maximum Non-Repetitive Peak Forward Surge Current

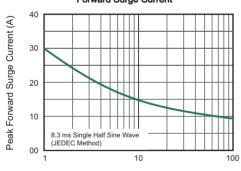


Fig.7 Peak Pulse Power Rating Curve

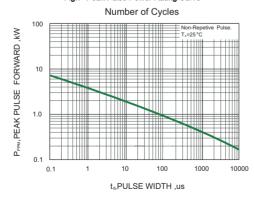


Fig.2 Typical Reverse Characteristics

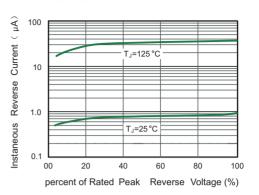


Fig.4 Typical Junction Capacitance

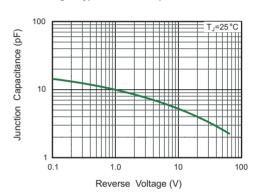
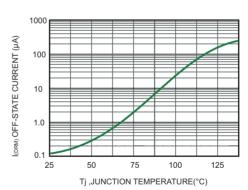
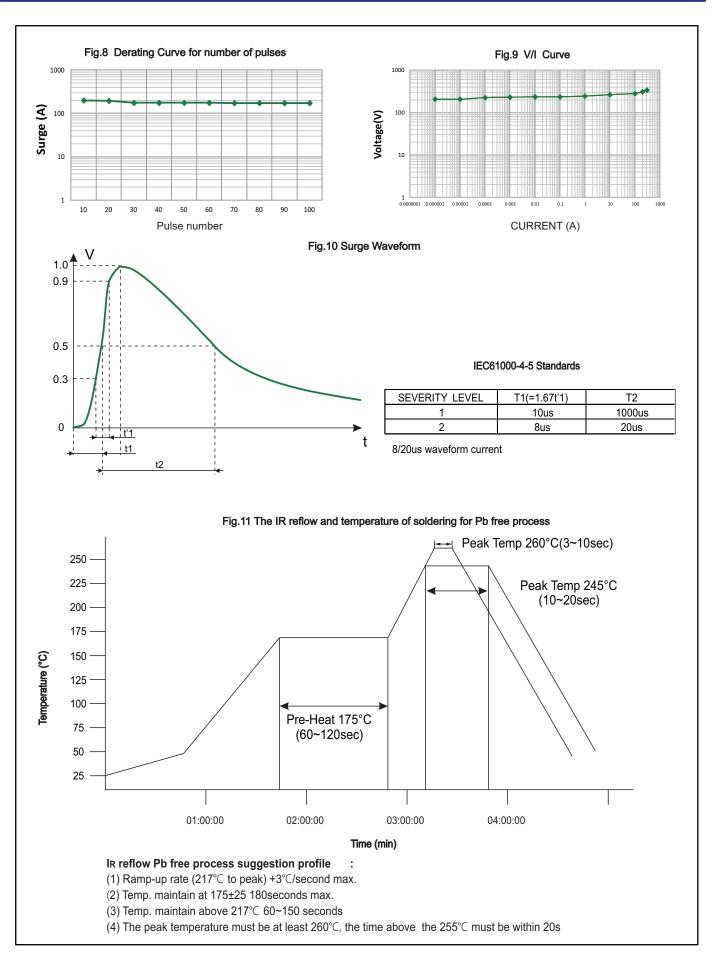


Fig.6 Off-State Current vs. Junction Temperature

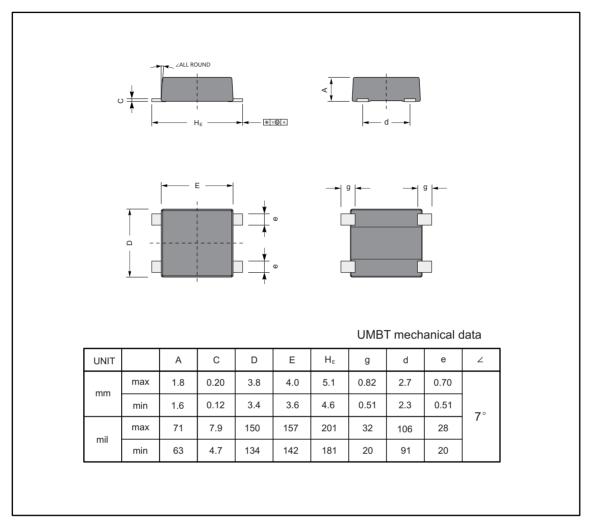




PACKAGE OUTLINE

Plastic surface mounted package; 4 leads

UMBT



The recommended mounting pad size

1.0×1.4 39×55

Marking

Type number	Marking code
STB110BS	T110B

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